NSN 5962-01-266-8060

Memory Microcircuit - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5962-01-266-8060

Body Length: 1.290 inches **Body Width:** Between 0.500 inches and 0.610 inches **Body Height:** 0.150 inches **Maximum Power Dissipation Rating:** 1.02 watts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Schottky and programmable and monolithic and bipolar **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 14 input **Case Outline Source And Designator:** D-3 mil-m-38510 **Terminal Surface Treatment:** Gold Voltage Rating And Type Per Characteristic: -0.5 volts power source and 7.0 volts power source **Time Rating Per Chacteristic:** 100.00 nanoseconds propagation delay time, low to high level output and 100.00 nanoseconds propagation delay time, high to low level output Memory Device Type: Rom **Precious Material And Location:** Terminal surfaces option gold **Precious Material:** Gold **Test Data Document:** 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.). **Terminal Type And Quantity:** 24 printed circuit Shelf Life:

N/a

NSN 5962-01-266-8060

Memory Microcircuit - Page 2 of 2

Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

A458a0

